## NSN 5962-01-329-7950

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View Online at https://aerobasegroup.com/nsn/5962-01-329-7950 **Body Length:** 1.290 inches **Body Width:** 0.610 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 950.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and bipolar and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Memory Device Type:** Rom **Test Data Document:** 81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 24 printed circuit **Specification Data:** 81349-mil-m-38510/209 government specification Shelf Life: N/a

No

**Unit Of Measure:** 

**Demilitarization:** 

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